July 2003

SL9R460P2, ISL9R460S2, ISL9R460S3S

## FAIRCHILD

SEMICONDUCTOR®

# ISL9R460P2, ISL9R460S2, ISL9R460S3S

## 4A, 600V Stealth<sup>™</sup> Diode

## **General Description**

The ISL9R460P2, ISL9R460S2 and ISL9R460S3S are Stealth<sup>™</sup> diodes optimized for low loss performance in high frequency hard switched applications. The Stealth<sup>™</sup> family exhibits low reverse recovery current (I<sub>RRM</sub>) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low  $I_{RRM}$  and short  $t_a$  phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the Stealth<sup>TM</sup> diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

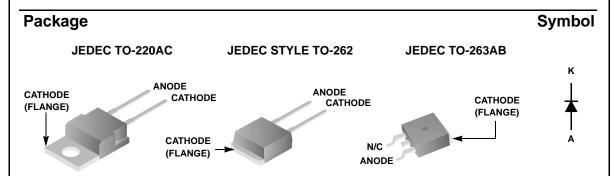
## Features

- Fast Recovery ......t<sub>rr</sub> < 20ns
- Avalanche Energy Rated

## Applications

- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode

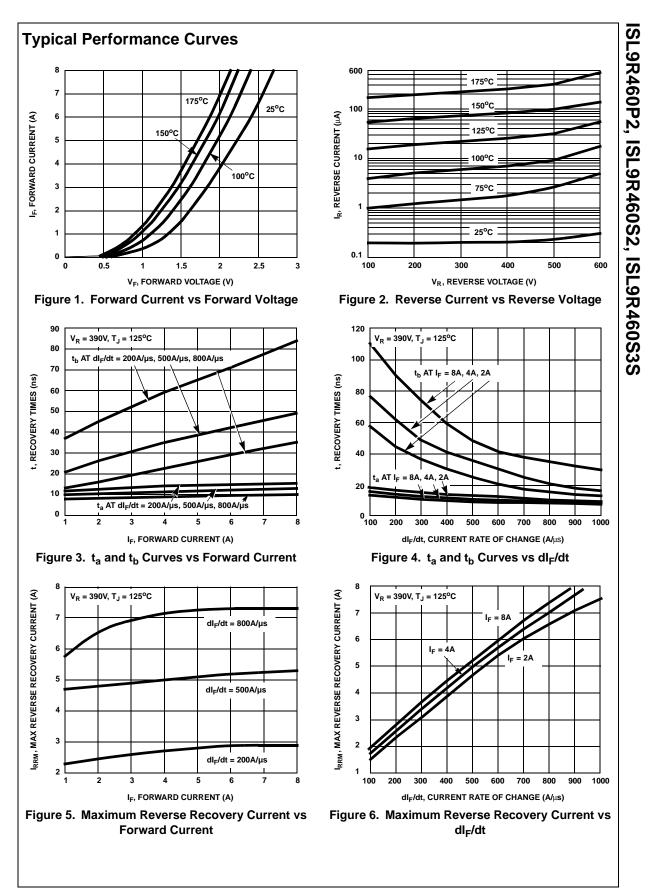
Formerly developmental type TA49408.



## Device Maximum Ratings T<sub>C</sub>= 25°C unless otherwise noted

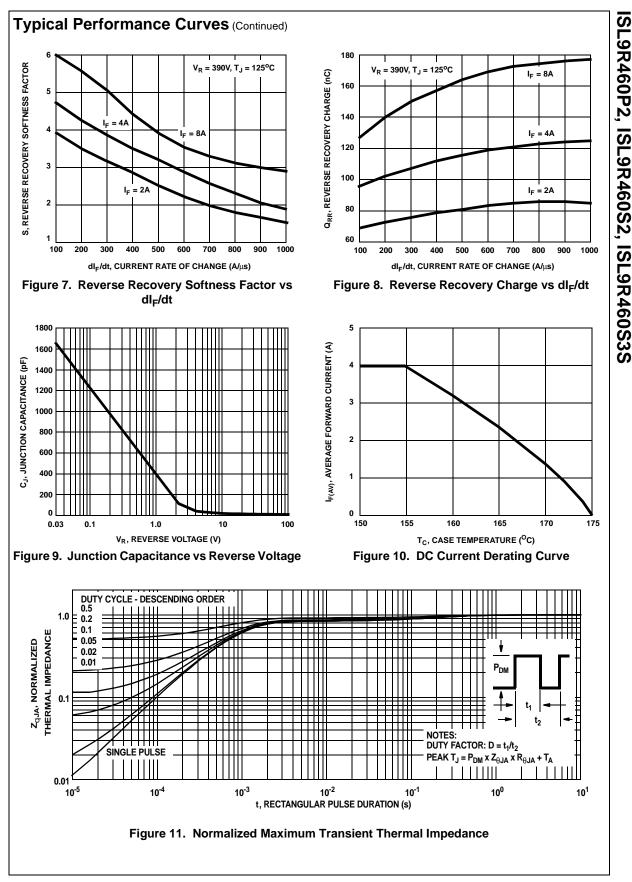
Symbol	Parameter	Ratings	Units
V <sub>RRM</sub> Peak Repetitive Reverse Voltage		600	V
V <sub>RWM</sub>	Working Peak Reverse Voltage	600	V
V <sub>R</sub>	DC Blocking Voltage	600	V
I <sub>F(AV)</sub>	Average Rectified Forward Current (T <sub>C</sub> = 155°C)	4	Α
I <sub>FRM</sub>	Repetitive Peak Surge Current (20kHz Square Wave)		А
I <sub>FSM</sub>	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	50	А
PD	Power Dissipation	58	W
E <sub>AVL</sub>	Avalanche Energy (0.5A, 80mH)	10	mJ
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to 175	°C
ΤL	Maximum Temperature for Soldering		
T <sub>PKG</sub>	Leads at 0.063in (1.6mm) from Case for 10s	300	°C
	Package Body for 10s, See Techbrief TB334	260	°C

Device	Marking	Device	Package Tape Widt		h		Quan	tity
R46	50P2	ISL9R460P2	TO-220AC	N/A			50	)
R46	60S2	ISL9R460S2	TO-262	N/A			50	
R460S3S			TO-263AB	N/A			50	
	0S3S		TO-263AB	24mm			800	0
	al Char	<b>acteristics</b> $T_C = 25^{\circ}C u$ Parameter	1	noted Conditions	Min	Тур	Max	Units
			Test	Conditions		тур	WIAX	Units
ff State	Characte	eristics					1	
۱ <sub>R</sub>	Instantaneo	ous Reverse Current	V <sub>R</sub> = 600V	$T_{C} = 25^{\circ}C$	-	-	100	μA
				T <sub>C</sub> = 125°C	-	-	1.0	mA
n State	Characte	eristics						
V <sub>F</sub>	Instantaneo	ous Forward Voltage	I <sub>F</sub> = 4A	$T_{\rm C} = 25^{\circ}{\rm C}$	-	2.0	2.4	V
•				T <sub>C</sub> = 125°C	-	1.6	2.0	V
namic	Characte	eristics						
CJ	Junction Ca		V <sub>R</sub> = 10V, I <sub>F</sub> = 0	)A	-	19	-	pF
-	4		K LOU, F					P.
vitchin	g Charac						•	
t <sub>rr</sub>	Reverse Recovery Time		$I_F = 1A, d_{IF}/dt = 100A/\mu s, V_R = 30V$		-	17	20	ns
			$I_F = 4A$ , $d_{IF}/dt = 100A/\mu s$ , $V_R = 30V$		-	19	22	ns
t <sub>rr</sub>		ecovery Time	$\begin{array}{c c c c c c c c c c c c c c c c c c c $		-		-	ns
I <sub>RRM</sub>		Reverse Recovery Current			-		-	A
Q <sub>RR</sub>		ecovery Charge			-		-	nC
t <sub>rr</sub>		ecovery Time			-		-	ns
S	Softness F				-		-	
	1	Reverse Recovery Current			-		-	A
Q <sub>RR</sub>		ecovery Charge			-		-	nC
t <sub>rr</sub>		ecovery Time			-	-	-	ns
S	Softness F					-	•	
I <sub>RRM</sub>		Reverse Recovery Current			-	A		
Q <sub>RR</sub>		ecovery Charge					-	nC
dl <sub>M</sub> /dt		di/dt during t <sub>b</sub>			-	500	-	A/µs
	Characte		T		ĩ			
$R_{\theta JC}$		esistance Junction to Case			-	-	2.6	°C/W
$R_{\theta JA}$		esistance Junction to Ambient			-	-	62	°C/W
		esistance Junction to Ambient			-	-	62	°C/W
R <sub>θJA</sub> R <sub>θJA</sub>		esistance Junction to Ambient	TO-263				62	°C/W



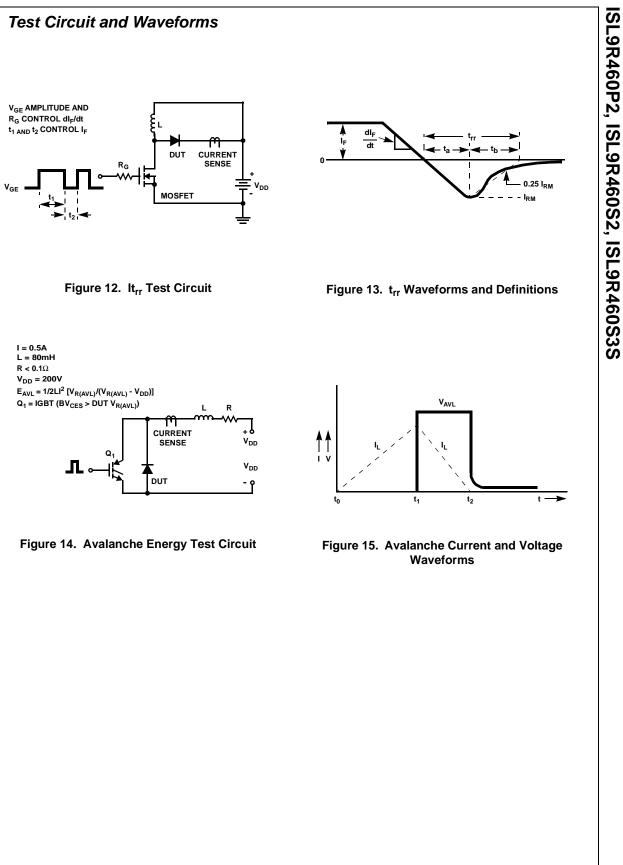
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E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	l <sup>2</sup> C™	OCX™	RapidConfigure™	UHC™
Across the board	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER <sup>®</sup>	VCX™
Programmable A	ctive Droop™	OPTOPLANAR™	SMART START™	

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